NSN 5961-00-470-9260

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-470-9260 **Inclosure Material:** Glass and metal **Overall Length:** 0.535 inches **End Application:** Wasp class Ihd; tarawa class Iha **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.878 inches **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 110.0 breakdown voltage, collector-to-base, emitter open and 90.0 breakdown voltage, collector-to-emitter, base open and 8.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 5.00 amperes source cutoff current and 30.00 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

NSN 5961-00-470-9260 Transistor - Page 2 of 2



Fiig:

A110a0